

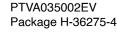
# PTVA035002EV

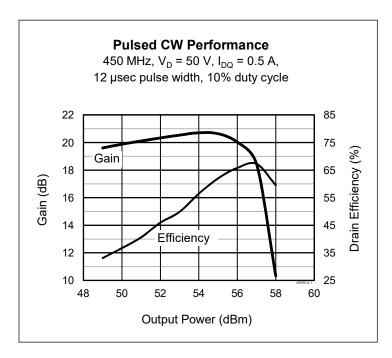
# Thermally-Enhanced High Power RF LDMOS FET 500 W, 50 V, 390 – 450 MHz

### **Description**

The PTVA035002EV LDMOS FET is designed for use in power amplifier applications in the 390 MHz to 450 MHz frequency band. Features include high gain and thermally-enhanced package with bolt-down flange. Manufactured with an advanced LDMOS process, this device provides excellent thermal performance and superior reliability.







#### **Features**

- Unmatched input and output
- · High gain and efficiency
- · Integrated ESD protection
- Human Body Model Class 2 (per ANSI/ESDA/ JEDEC JS-001)
- · Low thermal resistance
- Pb-free and RoHS-compliant
- Capable of withstanding a 13:1 load mismatch at 57 dBm under pulsed conditions: 12 µsec pulse width, 10% duty cycle

#### **RF Characteristics**

**Pulsed CW Class AB Characteristics** (not subject to production test, verified by design/characterization in the test fixture)  $V_{DD} = 50 \text{ V}$ ,  $I_{DQ} = 0.5 \text{ A}$ ,  $P_{OUT} = 500 \text{ W}$ , f = 450 MHz,  $12 \mu \text{sec}$  pulse width, 10% duty cycle

Characteristic	Symbol	Min	Тур	Max	Unit
Gain	$G_{ps}$	_	18	_	dB
Drain Efficiency	$\eta_{D}$	_	64	_	%

All published data at T<sub>CASE</sub> = 25°C unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!



#### **RF Characteristics**

#### Pulsed CW Characteristics (tested in the test fixture)

 $V_{DD}$  = 50 V,  $V_{GS}$  = 2.9 V,  $I_{DQ}$  = 0.0 A,  $P_{OUT}$  = 500 W, f = 450 MHz, 12  $\mu$ sec pulse width, 10% duty cycle

Characteristic	Symbol	Min	Тур	Max	Unit
Gain	G <sub>ps</sub>	14.75	15.5	_	dB
Drain Efficiency	o <sub>D</sub>	63	66	_	%

#### DC Characteristics (each side)

Characteristic	Conditions	Symbol	Min	Тур	Max	Unit
Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_{DS} = 10 \text{ mA}$	V <sub>(BR)DSS</sub>	105	_	_	V
Drain Leakage Current	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V}$	I <sub>DSS</sub>	_	_	1.0	$\mu$ A
	$V_{DS} = 105 \text{ V}, V_{GS} = 0 \text{ V}$	I <sub>DSS</sub>	_	_	10.0	$\mu$ A
On-State Resistance	$V_{GS} = 10 \text{ V}, V_{DS} = 0.1 \text{ V}$	R <sub>DS(on)</sub>	_	0.1	_	Ω
Operating Gate Voltage	$V_{DS} = 50 \text{ V}, I_{DQ} = 600 \text{ mA}$	$V_{GS}$	_	3.70	_	V
Gate Leakage Current	V <sub>GS</sub> = 10 V, V <sub>DS</sub> = 0 V	I <sub>GSS</sub>	_	_	1.0	μΑ

## **Maximum Ratings**

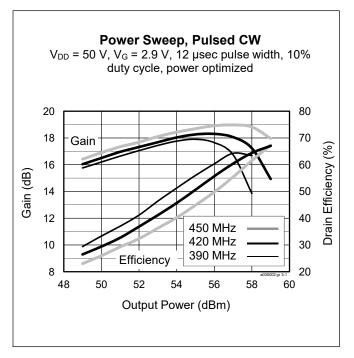
Parameter	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DSS</sub>	105	V
Gate-Source Voltage	$V_{GS}$	-6 to +12	V
Operating Voltage	$V_{DD}$	0 to +55	V
Junction Temperature	ТЈ	225	°C
Storage Temperature Range	T <sub>STG</sub>	-65 to +150	°C
Thermal Resistance (T <sub>CASE</sub> = 70°C, 300 W CW)	$R_{ hetaJC}$	0.20	°C/W

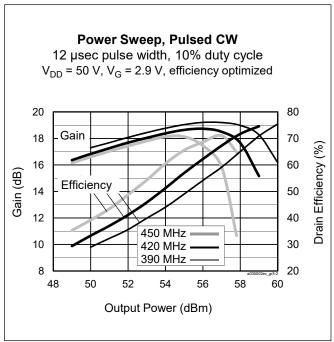
## **Ordering Information**

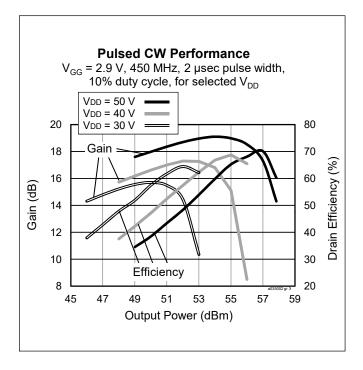
Type and Version	Order Code	Package Description	Shipping
PTVA035002EV V1 R0	PTVA035002EV-V1-R0	H-36275-4, bolt-down	Tape & Reel, 50pcs
PTVA035002EV V1 R250	PTVA035002EV-V1-R250	H-36275-4, bolt-down	Tape & Reel, 250pcs

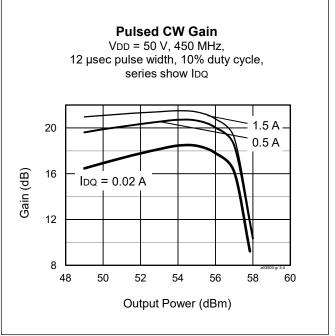


## Typical Performance (data taken in production test fixture)



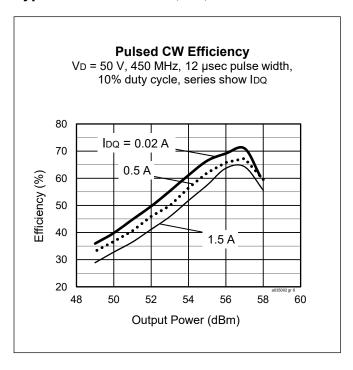






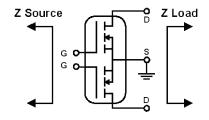


## Typical Performance (cont.)



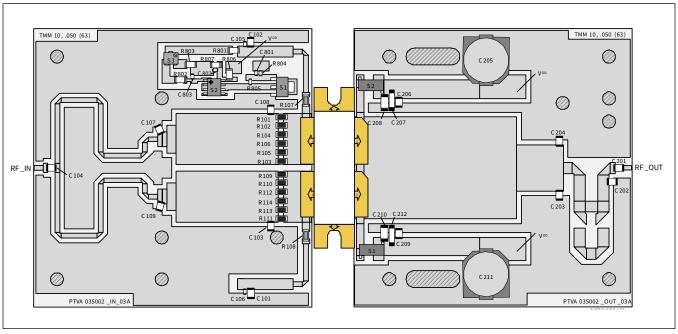
## **Broadband Circuit Impedance**

Frequency	<b>Z</b> Source $\Omega$		Z Loa	d $\Omega$
MHz	R	jΧ	R	jΧ
390	1.28	-0.12	1.80	-2.22
405	1.35	0.18	1.86	-1.91
420	1.43	0.48	1.92	-1.62
435	1.54	0.76	1.98	-1.35
450	1.67	1.04	2.02	-1.11





## Reference Circuit, 390 - 450 MHz



Reference circuit assembly diagram (not to scale)\*



## Reference Circuit (cont.)

#### **Reference Circuit Assembly**

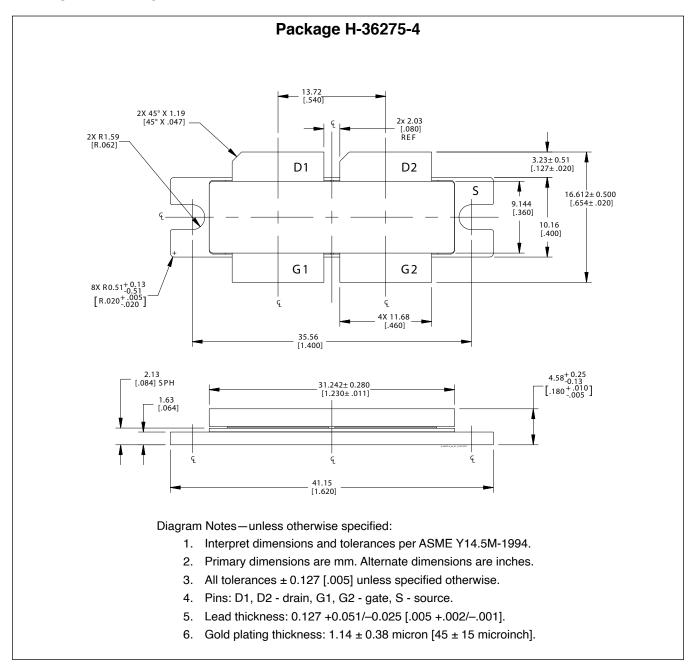
DUT	PTVA035002EV	
Test Fixture Part No.	LTN/PTVA035002EV	
PCB Rogers TMM10, 1.27 mm [0.050"] thick, 2 oz. copper, $\varepsilon_r = 9.2$		

#### **Components Information**

Components Information					
Component	Description	Suggested Manufacturer	P/N		
Input					
C101, C102, C104	Capacitor, 300 pF	ATC	ATC100B301KW200X		
C103, C108	Capacitor, 20 pF	ATC	ATC100B200KW500X		
C105, C106, C801, C802, C803	Capacitor, 1000 pF	Panasonic Electronic Components	ECJ-1VB1H102K		
C107, C109	Capacitor, 6.2 pF	ATC	ATC100B6R2CT500X		
R101, R102, R103, R104, R105, R106, R109, R110, R111, R112, R113, R114	Resistor, 5.6 Ω	Panasonic Electronic Components	ERJ-8GEYJ5R6V		
R107, R108	Resistor, 1000 $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ102V		
R801	Resistor, 100 $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ101V		
R802	Resistor, 2000 $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ202V		
R803	Resistor, 3600 $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ362V		
R804	Resistor, 1300 $\Omega$	Panasonic Electronic Components	ERJ-3GEYJ132V		
R805	Resistor, 1200 $\Omega$	Panasonic Electronic Components	ERJ-3GEYJ122V		
R806	Resistor, 2400 $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ242V		
R807	Resistor, 6200 $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ622V		
S1	Transistor	Infineon Technologies	BCP56		
S2	Voltage regulator	Texas Instruments	LM7805		
S3	Potentiometer	Bourns Inc.	3224W-1-202E		
Output					
C201, C206, C209	Capacitor, 300 pF	ATC	ATC100B301KW200X		
C202	Capacitor, 3 pF	ATC	ATC100B3R0CW500X		
C203, C204	Capacitor, 4.3 pF	ATC	ATC100B4R3CW500X		
C205, C211	Capacitor, 100 μF	United Chemi-Con	EMVE101ARA101MKE0S		
C207, C212	Capacitor, 10 µF	TDK Corporation	C5750X7S2A106M230KB		
C208, C210	Capacitor, 2.2 µF	TDK Corporation	C4532X7R2A225K230KA		
S1, S2	Inductor, 17.5 nH	Coilcraft	B06TGLB		



## **Package Outline Specifications**





#### **Revision History**

Revision	Date	Data Sheet Type	Page	Subjects (major changes since last revision)
01	2010-10-07	Advance	All	Data Sheet reflects advance specification for product development
02	2010-12-09	Advance	1, 2	Added ESD and VSWR information and revised conditions of test, Revise conditions of test.
03	2011-04-28	Preliminary	All	Convert to Preliminary Data Sheet, adding performance graphs, substantiating some characterizations.
04	2012-02-24	Production	All 4 – 9	Convert to final Data Sheet for production-released product. Add impedance data, Add reference circuit
05.1	2016-04-19	Production	1, 2	Added ESD rating, updated ordering information
05.2	2016-06-08	Production	2	Updated ordering information to include R250
05.3	2017-02-02	Production	2	Added operating voltage and updated junction temperature
06	2018-06-12	Production	All	Converted to the Data Sheet



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